

View Online at <https://aerobasegroup.com/nsn/5961-01-162-4615>

**Inclosure Material:**

Metal

**Overall Length:**

1.573 inches

**Overall Height:**

0.450 inches

**Overall Width:**

1.050 inches

**End Application:**

6625-01-022-5859

**Mounting Facility Quantity:**

2

**Internal Configuration:**

Field effect-dual gate

**Joint Electronic Device Engineering Council/jedec/case Outline Designation:**

To-3

**Electrode Internally-electrically Connected To Case:**

Drain

**Mounting Method:**

Unthreaded hole

**Features Provided:**

Hermetically sealed case

**Semiconductor Material:**

Silicon

**Voltage Rating In Volts Per Characteristic:**

200.0 drain to source voltage and 200.0 drain to gate voltage

**Current Rating Per Characteristic:**

9.00 amperes source cutoff current of standard range

**Power Rating Per Characteristic:**

75.0 watts small-signal input power, common-collector absolute

**Maximum Operating Temperature Per Measurement Point:**

150.0 degrees celsius junction

**Terminal Type And Quantity:**

2 pin and 1 case

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fig:**

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